

1. Global joint venture starts operations as WeEn Semiconductors

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As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

In this document where the previous NXP references remain, please use the new links as shown below.

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Thank you for your cooperation and understanding,

WeEn Semiconductors





1. General description

Planar passivated Silicon Controlled Rectifier in a SOT54 (TO-92) plastic package. This SCR is designed to be interfaced directly to microcontrollers, logic ICs and other low power gate trigger circuits.

2. Features and benefits

- · Planar passivated for voltage ruggedness and reliability
- Sensitive gate
- Direct triggering from low power drivers and logic ICs

3. Applications

- · General purpose switching and phase control
- Low power circuits

4. Quick reference data

Table 1. Quick reference data

Table I. Qui	ck reference uala					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	400	V
V _{RRM}	repetitive peak reverse voltage		-	-	400	V
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	-	8	А
		half sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 8.3 \text{ ms}$	-	-	9	А
Tj	junction temperature		-	-	125	°C
I _{T(AV)}	average on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 1</u>	-	-	0.5	A
I _{T(RMS)}	RMS on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	-	0.8	A
Static chara	acteristics			·		
I _{GT}	gate trigger current	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 7</u>	-	50	200	μA
Dynamic ch	aracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 268 V; T _j = 125 °C; R _{GK} = 1 kΩ; (V_{DM} = 67% of V_{DRM}); exponential waveform; Fig. 12	500	800	-	V/µs
		1	1			

5. Pinning information

Table 2.	Pinning int	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode		А -Ы -К
2	G	gate		G sym037
3	A	anode	∏∏∏ □ □ □ 3 2 1 TO-92 (SOT54)	<i></i>

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
BT149D	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54			

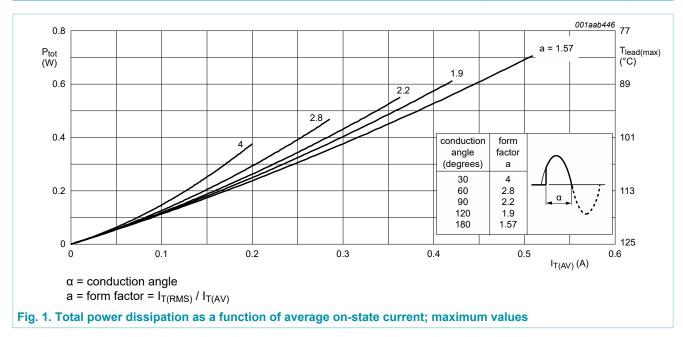
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7. Limiting values

Table 4. Limiting values

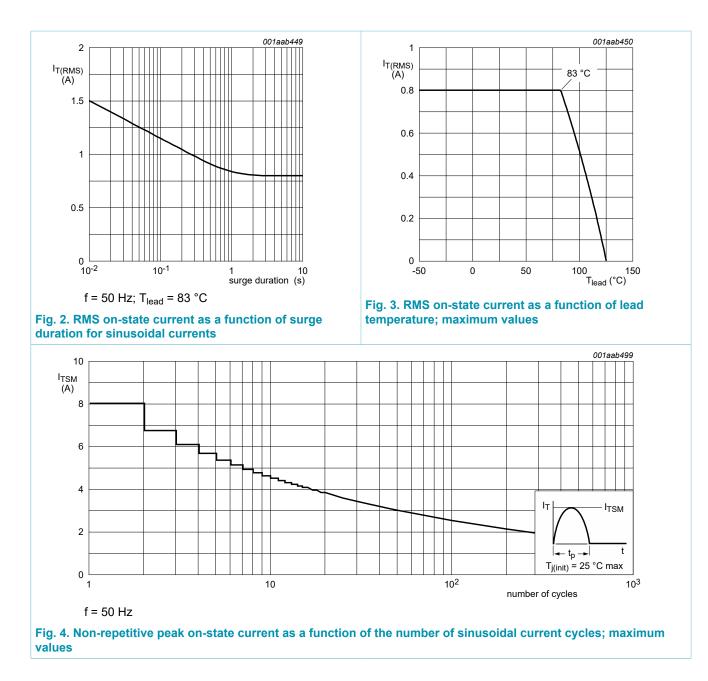
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	400	V
V _{RRM}	repetitive peak reverse voltage		-	400	V
I _{T(AV)}	average on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 1</u>	-	0.5	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 2; Fig. 3</u>	-	0.8	А
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$; Fig. 4; Fig. 5	-	8	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms	-	9	А
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	0.32	A²s
dl _T /dt	rate of rise of on-state current	$I_T = 2 \text{ A}; I_G = 10 \text{ mA}; \text{dI}_G/\text{dt} = 100 \text{ mA}/\mu\text{s}$	-	50	A/µs
I _{GM}	peak gate current		-	1	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	2	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C



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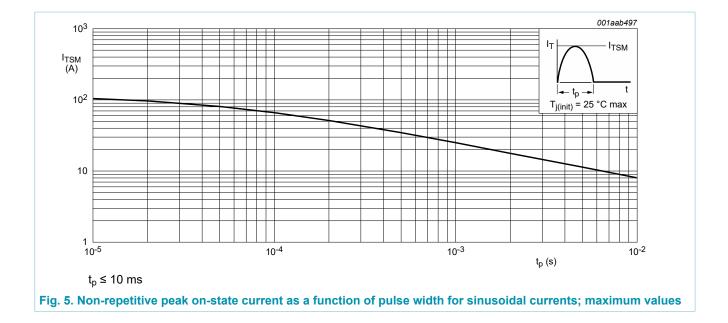
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Product data sheet

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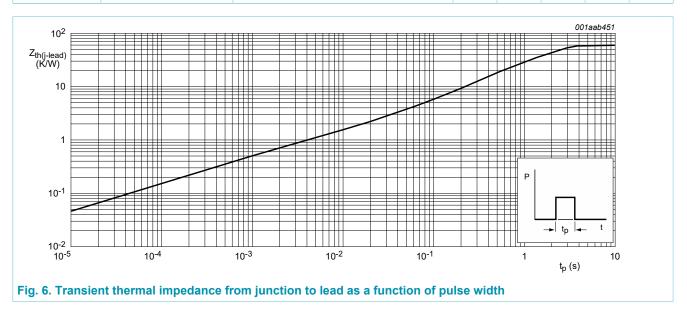
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8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-lead)}	thermal resistance from junction to lead	<u>Fig. 6</u>	-	-	60	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	printed circuit board mounted: lead length = 4 mm	-	150	-	K/W



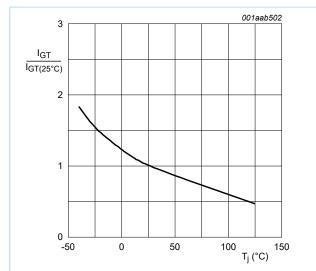
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9. Characteristics

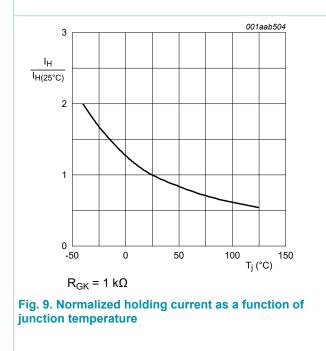
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · · · · · · · · · · · · · · · · · ·				
I _{GT}	gate trigger current	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 7</u>	-	50	200	μA
L	latching current	V_D = 12 V; I _G = 0.5 mA; T _j = 25 °C; R _{GK(ext)} = 1 kΩ; Fig. 8	-	2	6	mA
I _H	holding current	V_D = 12 V; T _j = 25 °C; R _{GK(ext)} = 1 k Ω ; Fig. 9	-	2	5	mA
V _T	on-state voltage	I _T = 1.2 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.25	1.7	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 11</u>	-	0.5	0.8	V
		V _D = 400 V; I _T = 10 mA; T _j = 125 °C; <u>Fig. 11</u>	0.2	0.3	-	V
I _D	off-state current	V _D = 400 V; R _{GK(ext)} = 1 kΩ; T _j = 125 °C	-	0.05	0.1	mA
I _R	reverse current	V_R = 400 V; T _j = 125 °C; $R_{GK(ext)}$ = 1 k Ω	-	0.05	0.1	mA
Dynamic ch	naracteristics	· · · · · · · · · · · · · · · · · · ·				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 268 V; T _j = 125 °C; R _{GK} = 1 kΩ; (V_{DM} = 67% of V_{DRM}); exponential waveform; Fig. 12	500	800	-	V/µs
		V_{DM} = 268 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 12	-	25	-	V/µs
t _{gt}	gate-controlled turn-on time	$\begin{split} I_{TM} &= 2 \text{ A}; \text{ V}_{D} = 400 \text{ V}; \text{ I}_{G} = 10 \text{ mA}; \text{ dI}_{G} \text{/} \\ \text{dt} &= 0.1 \text{ A} \text{/} \mu \text{s}; \text{ T}_{j} = 25 ^{\circ}\text{C} \end{split}$	-	2	-	μs
t _q	commutated turn-off time	V_{DM} = 268 V; T _j = 125 °C; I _{TM} = 1.6 A; V _R = 35 V; (dI _T /dt) _M = 30 A/µs; dV _D / dt = 2 V/µs; R _{GK(ext)} = 1 kΩ	-	100	-	μs

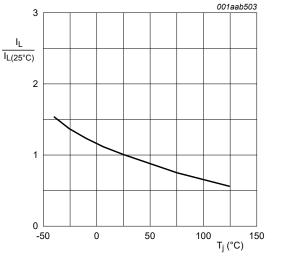
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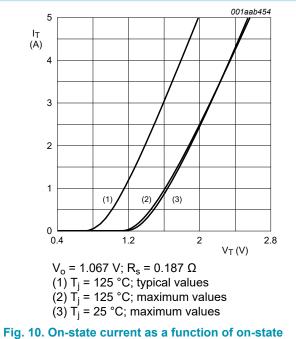








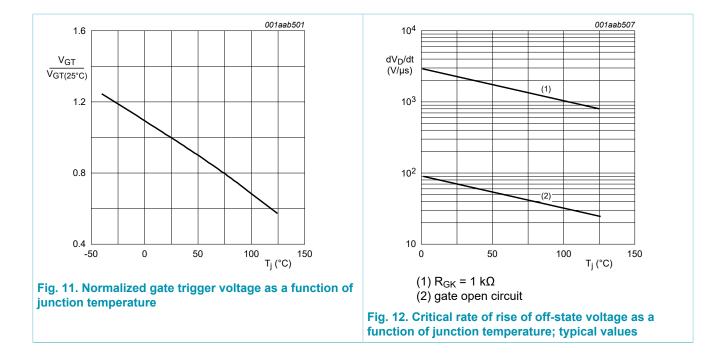




voltage

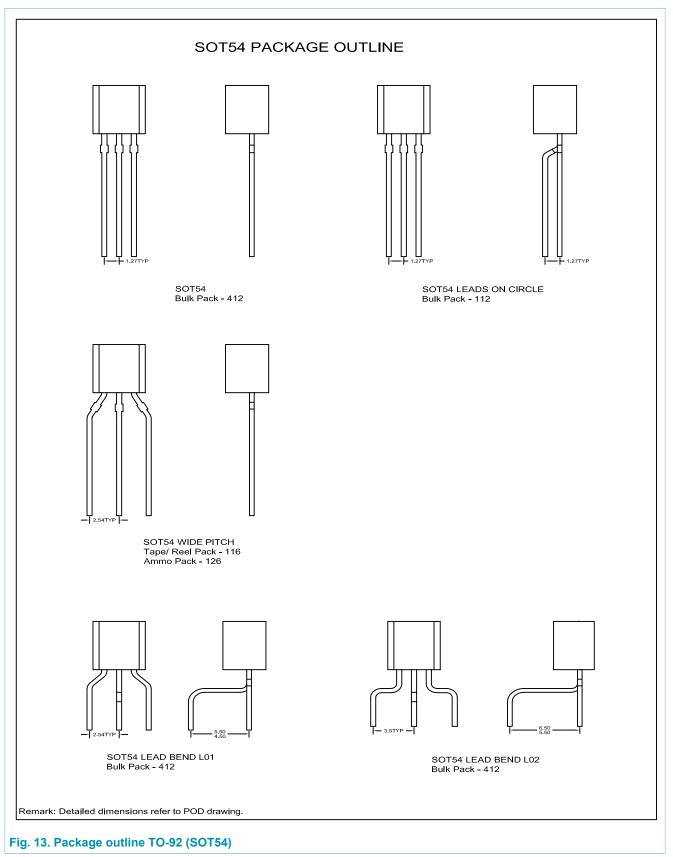
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10. Package outline



Product data sheet

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11. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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